

Amendments to the Specification

Please add the following after the title before line 1 of page 1:

1. Field of the Invention

Please add the following between lines 6-8 of page 1:

2. Background of the Invention

Please add the following between lines 7-9 of page 3:

SUMMARY OF THE INVENTION

Please add the following between lines 20-22 of page 6:

BRIEF DESCRIPTION OF THE DRAWINGS

Please add the following between lines 7-9 of page 8:

Figure 10 illustrates a top view and a cross section view of a FBAR in which an acoustic reflective stack is used.

DETAILED DESCRIPTION OF THE EXEMPLARY EMBODIMENTS

Please replace the paragraph beginning on page 12, line 14, with the following rewritten paragraph:

FBARs which are used as an FBAR in series 10 and an FBAR in parallel 11, are not restricted to be an FBAR which comprises an etched hole on Si wafer 20 at the backside of a bottom electrode 25. An air gap or a Bragg reflector (acoustic reflective stack) 29 as shown in Figure 10 may be used at the backside of a bottom electrode 25 instead of an etched hole on Si wafer 20. Hence a Si wafer 20 is not necessarily the only type of substrate which can be used for the FBARs.

Please replace the Abstract with the attached amended Abstract.

An electric filter comprises a plurality of thin film bulk acoustic resonators (10, 11) arranged in series and in parallel which have different thicknesses (T) of one or more non-piezoelectric layers, for example top electrode (24).

~~To be accompanied, when published, by Figures 1 and 2 of the drawings.~~